



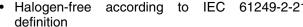
Fast Switching Diodes

Features

- · Fast switching speed
- · High reliability
- · High conductance
- For general purpose switching applicions
- AEC-Q101 qualified

 Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Halogen-free according to IEC 61249-2-21





Mechanical Data

Case: DO-35

Weight: approx. 125 mg Cathode Band Color: black Packaging codes/options:

TR/10 k per 13" reel (52 mm tape), 50 k/box TAP/10 k per Ammopack (52 mm tape), 50 k/box

Parts Table

	Part	Ordering code	Type Marking	Remarks	
-	1N914	1N914-TR or 1N914-TAP	1N914	Tape and Reel/Ammopack	

COMPLIANT HALOGEN

FREE

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Non repetitive peak reverse voltage		V_{RM}	100	V
Repetitive peak reverse voltage		V _{RRM}	75	V
Working peak reverse voltage		V _{RWM}	75	V
DC blocking voltage		V _R	75	V
RMS Reverse voltage		V _{R(RMS)}	53	V
Forward continuous current		I _F	300	mA
Average rectified current	Half wave rectification with resistive load and f > 50 MHz	I _{FAV}	200	mA
Non repetitive peak forward	t = 1 s	I _{FSM}	1	Α
surge current	t = 1 μs	I _{FSM}	4	Α
Power dissipation	I = 4 mm, T _L = 25 °C	P _{tot}	500	mW

Thermal Characteristics

T_{amb} = 25 °C unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	I = 4 mm, T _L = constant	R_{thJA}	300	K/W
Junction temperature		T _j	+ 175	°C
Storage temperature range		T _{stg}	- 65 to + 175	°C

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Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I _F = 10 mA	V_{F}			1000	mV
Breakdown voltage	I _R = 100 μA	V _(BR)	100			V
	V _R = 75 V	I _R			5	μΑ
Peak reverse current	$V_R = 20 \text{ V}, T_j = 150 ^{\circ}\text{C}$	I _R			50	μΑ
	V _R = 20 V	I _R			25	nA
Diode capacitance	$V_R = 0$, $f = 1 MHz$	C _D			4	pF
Reverse recovery time	$I_F = 10 \text{ mA to } I_R = 1 \text{ mA},$ $V_R = 6 \text{ V}, R_L = 100 \Omega$	t _{rr}			4	ns

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

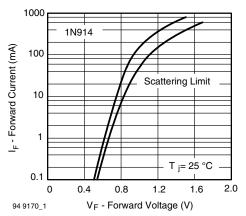


Figure 1. Forward Current vs. Forward Voltage

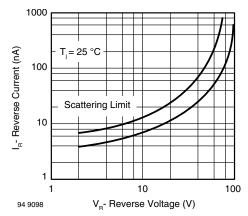
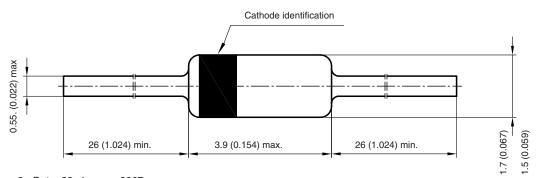


Figure 2. Reverse Current vs. Reverse Voltage

Package Dimensions in millimeters (inches): DO-35



Rev. 6 - Date: 29. January 2007 Document no.: 6.560-5004.02-4

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Document Number: 91000 Revision: 18-Jul-08

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